



## NIVERSIDAD DEGRANADA

# Ambipolar radiofrequency applications for the next generation of microwave engineers

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Introduction

Graphene and related materials (GRM) based electronic devices could offer big opportunities in many fields such as highfrequency electronics and they have become potential candidates for the deployment of emergent flexible and wearable electronics. This scenario is of particular relevance for the students in telecommunications and electronics degrees, who will face the new challenges arising with this potential paradigm shift in the prevailing electronic technology.

## **Objectives**

The technology computer-aided design (TCAD) tools can be exploited by the engineering students to explore ambipolar electronics opening the possibility to 1) redesigning and simplifying of conventional circuits; and 2) seeking of new functionalities for analogue radiofrequency electronics.

## Methods

By using TCAD tools of graphene field-effect transistors embedded into commercial microwave circuit simulators usually employed by students in telecommunications and electronics degrees, we present **new insights** for the design of graphene-based RF frequency multipliers and mixers that specifically exploit the inherent intrinsic ambipolarity of graphene from an engineering perspective.

#### Results

The use of TCAD tools has resulted in (i) increasing the interest of students for emergent novel technologies; (ii) the design and exploration of **new concepts for radiofrequency designs** such as a frequency tripler (Figure 2) and a subharmonic mixer (Figure 3); and (iii) **providing better understanding** in the design of microwave integrated circuits.  $Z_{in,\lambda/4}$  $\lambda_{LO}/4$ 

VGG

GFET

0.5

 $V_{DD} \leftarrow$ 

400 (Ψη) <sup>QQ</sup><sub>I</sub>

600

200

0

 $R_X$ 

 $\sim \sim$ 

 $I_{DD}$ 

GFET2

 $f_{out} = 3f_{in}$ 

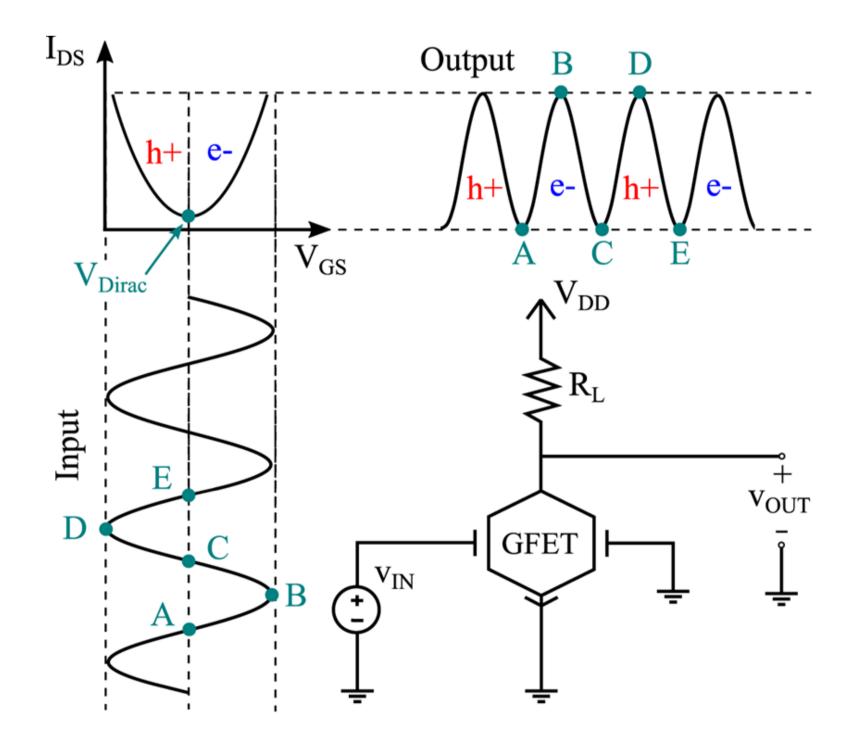
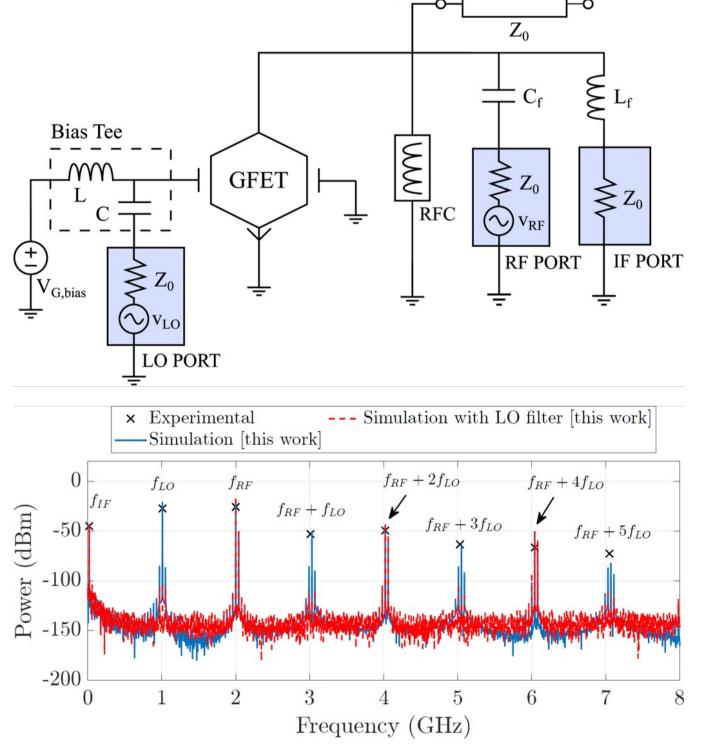


Figure 1. Ambipolar operating principle



1.5

 $V_{GG}(\mathbf{V})$ 



**Figure 3**. Subharmonic mixer and  $\lambda/4$ filter for radiofrequency communications

#### Conclusion

Ambipolar electronics offers huge opportunities for the future design of microwave integrated circuits. In this context, we have implemented a set of circuit models to be exploited in conventional circuit simulators used in engineering degrees to seek out new functionalities, to simplify the circuit topologies or even to improve the circuit performance. This work gives insights for engineering students about how the accurate control of graphene ambipolarity can be exploited for the development of frequency multipliers and mixers.

### References

Medina-Rull, A., Pasadas, F., Marin, E. G., Toral-Lopez, A., Cuesta, J., Godoy, A., Jiménez, D., Ruiz, F. G., (2020). A Graphene Field-Effect Transistor Based Analogue Phase Shifter for High-Frequency Applications. *IEEE Access*, 8, 209055–209063. https://doi.org/10.1109/ACCESS.2020.3038153

The TCAD tools for GFET circuit simulations are available from the corresponding authors upon reasonable request (<u>fpasadas@ugr.es</u>; <u>egmarin@ugr.es</u>).